

# Midium Power Transistors (-50V / -2A)

## 2SAR553P

## Structure

PNP Silicon epitaxial planar transistor

#### Features

 Low saturation voltage, typically V<sub>CE (sat)</sub> = -0.4V (Max.) (I<sub>C</sub> / I<sub>B</sub>=-700mA / -35mA)
High speed switching

#### Applications

Driver

#### • Packaging specifications

Туре	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SAR553P		0

## • Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V <sub>CBO</sub>	-50	V
Collector-emitter voltage		V <sub>CEO</sub>	-50	V
Emitter-base voltage		$V_{EBO}$	-6	V
Collector current	DC	Ι <sub>C</sub>	-2	A
	Pulsed	I <sub>CP</sub> *1	-4	A
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2	W
Junction temperature		Tj	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to 150	°C

## • Dimensions (Unit : mm)



#### • Inner circuit (Unit : mm)



\*1 Pw=10ms, Single Pulse

\*2 Each terminal mounted on a recommended land.

\*3 Mounted on a ceramic board. (40x40x0.7mm<sup>3</sup>)

## •Electrical characteristic (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	-50	-	-	V	$I_{c}$ = -1mA	
Collector-base breakdown voltage	BV <sub>CBO</sub>	-50	-	-	V	I <sub>c</sub> = -100μA	
Emitter-base breakdown voltage	BV <sub>EBO</sub>	-6	-	-	V	I <sub>E</sub> = -100μΑ	
Collector cut-off current	I <sub>CBO</sub>	-	-	-1	μA	V <sub>CB</sub> = -50V	
Emitter cut-off current	I <sub>EBO</sub>	-	-	-1	μA	V <sub>EB</sub> = -4V	
Collector-emitter staturation voltage	V <sub>CE(sat)</sub> *1	-	-200	-400	mV	I <sub>C</sub> = -700mA, I <sub>B</sub> = -35mA	
DC current gain	h <sub>FE</sub>	180	-	450	-	V <sub>CE</sub> = -2V, I <sub>C</sub> = -50mA	
Transition frequency	f <sub>T</sub> *1	-	320	-	MHz	V <sub>CE</sub> = -10V I <sub>E</sub> =300mA, f=100MHz	
Collector output capacitance	C <sub>ob</sub>	-	22	-	pF	V <sub>CB</sub> = -10V, I <sub>E</sub> =0A f=1MHz	
Turn-on time	t <sub>on</sub> *2	-	45	-	ns	1 1 1 1 1 00 1	
Storage time	t <sub>stg</sub> * <sub>2</sub>	-	220	-	ns	I <sub>C</sub> = -1A,I <sub>B1</sub> = -100mA, I <sub>B2</sub> =100mA,V <sub>CC</sub> <u>~</u> -10V	
Fall time	t <sub>f</sub> *2	-	35	-	ns	182-100mA, VCC - 10V	

\*1 Pulsed

\*2 See switching time test circuit

## •Electrical characteristic curves



## •Switching time test circuit



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